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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/642,666	08/19/2003	Masahisa Sonoda	04329.3116	3478		
7	590 02/10/2005		EXAM	EXAMINER		
Finnegan, Henderson, Farabow,			LOKE, STEV	LOKE, STEVEN HO YIN		
Garrett & Duni	•					
1300 I Street, N	N.W.	ART UNIT	PAPER NUMBER			
Washington, DC 20005-3315			2811	· · · · · · · · · · · · · · · · · · ·		
			DATE MAILED: 02/10/2005			

Please find below and/or attached an Office communication concerning this application or proceeding.

					MV_			
		Applicati	on No.	Applicant(s)	7112			
	Office Action Summer	10/642,6	66	SONODA ET AL.				
	Office Action Summary	Examine	r	Art Unit				
	The MAN INC DATE of the	Steven Lo	=	2811				
	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).								
Status								
1)🛛 🗆	Responsive to communication(s) filed	l on <u>07 January 200</u>	<u>05</u> .					
2a)□	nis action is FINAL. 2b) 🗵 This action is non-final.							
_	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Dispositio	on of Claims							
5) [4) Claim(s) 1-22 is/are pending in the application. 4a) Of the above claim(s) 3 and 6-22 is/are withdrawn from consideration. 5) Claim(s) is/are allowed. 6) Claim(s) 1,2 and 5 is/are rejected. 7) Claim(s) 4 is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement. 							
Application	on Papers				·			
9)☐ The specification is objected to by the Examiner.								
	10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.							
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.							
Priority u	nder 35 U.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 								
2) Notice 3) Inform	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PT ation Disclosure Statement(s) (PTO-1449 or P No(s)/Mail Date 8/19/03.		4) Interview Summary Paper No(s)/Mail Do 5) Notice of Informal P 6) Other:	ate)-152) 			

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1. Applicant's election without traverse of claims 1, 2, 4 and 5 in the reply filed on 1/7/05 is acknowledged.

- 2. Claims 3 and 6-22 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected species and invention, there being no allowable generic or linking claim. Election was made without traverse in the reply filed on 9/29/04 and 1/7/05.
- 3. The lengthy specification has not been checked to the extent necessary to determine the presence of all possible minor errors. Applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.
- 4. Claim 1 is objected to because of the following informalities: lines 15-16, the phrase "said plurality of the grooves" is unclear whether it is being referred to "said plurality of grooves". Appropriate correction is required.
- 5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. Claims 1, 2 and 5 are rejected under 35 U.S.C. 103(a) as being obvious over Arai et al.

The applied reference has a common assignee with the instant application.

Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art only under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 103(a) might be overcome

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by: (1) a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not an invention "by another"; (2) a showing of a date of invention for the claimed subject matter of the application which corresponds to subject matter disclosed but not claimed in the reference, prior to the effective U.S. filing date of the reference under 37 CFR 1.131; or (3) an oath or declaration under 37 CFR 1.130 stating that the application and reference are currently owned by the same party and that the inventor named in the application is the prior inventor under 35 U.S.C. 104, together with a terminal disclaimer in accordance with 37 CFR 1.321(c). For applications filed on or after November 29, 1999, this rejection might also be overcome by showing that the subject matter of the reference and the claimed invention were, at the time the invention was made, owned by the same person or subject to an obligation of assignment to the same person. See MPEP § 706.02(I)(1) and § 706.02(I)(2).

In regards to claim 1, Arai et al. disclose a nonvolatile semiconductor memory device in figs. 35 and 36. It comprising: a plurality of nonvolatile memory elements formed on element regions respectively isolated by element isolation regions [118] on a main surface of a first conductive type (p-type) semiconductor substrate [103]; the nonvolatile semiconductor memory elements comprising: a gate insulating film [105] formed on the main surface of the semiconductor substrate; a plurality floating electrodes [106, 119] formed along a first direction (fig. 35) on the gate insulating film; a plurality of grooves [117] formed among said plurality floating electrodes; groove insulating films [120] filled in said plurality of grooves; an impurity diffusion region [124]

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formed along a second direction (fig. 36) so as to sandwich the floating electrodes; interelectrode insulating films [120] formed along the first direction on the plurality of floating electrodes and the groove insulating films; and control electrodes [121, 122] formed on the interelectrode insulating films.

Figs. 35 and 36 of Arai et al. differ from the claimed invention by not showing the impurity diffusion has a second conductivity type.

Fig. 10 of Arai et al. show the source/drain diffusion regions [26] of a NAND cell type EEPROM has n-type conductivity (second conductivity type).

Since figs. 35, 36 and 10 of Arai et al. teach a NAND cell type EEPROM formed in a p-type region, it would have been obvious to have the n-type source/drain region of fig. 10 of Arai et al. in figs. 35 and 36 of Arai et al. because it provides an operational n-channel type NAND cell type EEPROM transistor in a p-type substrate.

In regards to claim 2, Arai et al. further disclose the groove insulating films [120] filled in the groove is formed of the same insulating material (ONO) as the interelectrode insulating film.

In regards to claim 5, Arai et al. further disclose the interelectrode insulating film [120] and the groove insulating film includes an ONO insulating film.

- 7. Claim 4 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 8. The following is a statement of reasons for the indication of allowable subject matter: The major difference in the claims not found in the prior art of record is a width

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of the groove is less than or equal to 1.6 times a film thickness of the interelectrode insulating film.

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Steven Lole

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Steven Loke whose telephone number is (571) 272-1657. The examiner can normally be reached on 7:50 am to 5:20 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (571) 272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

February 5, 2005